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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/819,621	03/29/2001	Kenji Todori	P 280037 T7K0-00S105-1	4396
909	7590 08/16/2004		EXAMINER	
PILLSBURY WINTHROP, LLP			ANGEBRANNDT, MARTIN J	
P.O. BOX 10 MCLEAN, \			ART UNIT	PAPER NUMBER
,			1756	

DATE MAILED: 08/16/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	9				
Office Action Summany	09/819,621	TODORI ET AL.	/				
Office Action Summary	Examiner	Art Unit					
	Martin J Angebranndt	1756					
The MAILING DATE of this communication app Period for Reply	pears on the cover sheet with the	correspondence address -					
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1: after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply If NO period for reply is specified above, the maximum statutory period of Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be to within the statutory minimum of thirty (30) dawill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDON	imely filed ys will be considered timely. In the mailing date of this communica ED (35 U.S.C. § 133).	ation.				
Status							
1) Responsive to communication(s) filed on 6/18/	<u>′2004</u> .						
2a)⊠ This action is FINAL . 2b)☐ This	action is non-final.						
3) Since this application is in condition for allowar	3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
closed in accordance with the practice under E	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.						
Disposition of Claims							
4)	wn from consideration.						
Application Papers							
9) The specification is objected to by the Examine	r.						
10) The drawing(s) filed on is/are: a) acc	epted or b)⊡ objected to by the	Examiner.					
Applicant may not request that any objection to the		, ,					
Replacement drawing sheet(s) including the correct 11) The oath or declaration is objected to by the Ex							
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applica rity documents have been receiv u (PCT Rule 17.2(a)).	tion No red in this National Stage					
Attachment(s)							
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summar Paper No(s)/Mail D 5) Notice of Informal 6) Other:						

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1. The response provided by the applicant has been read and given careful consideration.

Responses to the arguments are presented after the first rejection to which the argument is directed. Rejection of the previous office action not repeated below are withdrawn based upon the arguments and amendments of the applicant.

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims 1-5,7-14,16-19,21-24 and 26-28 are rejected under 35 U.S.C. 103(a) as being unpatentable over Iida et al. EP 0580346, in view of Murray et al., "synthesis and Charachotrization of nearly monodisperse CdE (E=s,se,te) semiconductor nanocrystallites", JACS, Vol. 115(19) pp. 8706-8715 (1993) and Liz-Marzan, et al. WO 99/291934.

Iida et al. EP 0580346 teaches a high density optical disk with a shutter layer of semiconductor particles dispersed in a glass or polymeric matrix over coated with a reflective layer as shown in figure 2. Useful semiconductor materials in amounts of 1-80 mol % and having sizes of 0.1 to 50 nm are disclosed. (3/11-33) The use of polymers as the matrix materials, including PMMA, polycarbonate, polystyrenes, polyolefins, and epoxies is disclosed as its the formation of the layer from a solvent based solution. (3/34-41 and 4/3-13). The reflective layer may be various metals including Ag, Au, Al and Cu. (4/44-51). The use of protective layer is also disclosed. (4/52-57). Another embodiment is shown in figure 3.

Murray et al., "synthesis and Characterization of nearly monodisperse CdE (E=s,se,te) semiconductor nanocrystallites", JACS, Vol. 115(19) pp. 8706-8715 (1993), teaches the

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synthesis of nanocrystalline semiconductor particles to reduce polydispersity and improve the uniformity of surface derivitazation (capping). (page 8706, right column) The ease of dispersal in various solvents (alkanes, aromatrics, long chain alcohols, etc) is disclosed. (page 8707, left column). The use of these in optical field is disclosed. (page 8706, left column) The sizes of the particles is between 1.5 and 11.5 nm (page 8707, left column). The surface derivatization is disclosed as preventing flocculation (page 8708, right column). The particles sizes as disclosed as affecting the absorption properties as shown in figure 3.

Liz-Marzan, et al. WO 99/291934 teaches methods for stabilizing particles to prevent agglomeration/coalescence without affecting their properties.(2/16-22). The ligands which bond to the surface of the particles may be thiols, amines, phosphines, phosphates, borates, carboxylates, silicates, siloxy, ... (3/10-28). The stabilization of CdS and other semiconducor materials, having sizes of less than 100 nm, preferably less than 40 nm is disclosed. (7/24-8/17 and examples) The use of this technique for stabilizing the particles for optical uses in a variety of matrices, including polymers, is disclosed. (13/18-23).

It would have been obvious to one skilled in the art to modify the article of Iida et al. EP 0580346 by using the processes of either Murray et al., "synthesis and Charachotrization of nearly monodisperse CdE (E=s,se,te) semiconductor nanocrystallites", JACS, Vol. 115(19) pp. 8706-8715 (1993) with a reasonable expectation of gaining in monodispersity and stability in both solvents and the polymeric matrix based upon the teachings of Murray et al., "synthesis and Charachotrization of nearly monodisperse CdE (E=s,se,te) semiconductor nanocrystallites", JACS, Vol. 115(19) pp. 8706-8715 (1993) and Liz-Marzan, et al. WO 99/291934 of the

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desirability of stabilizing the particles in either solvents or polymeric matrices and the disclosure of the dispersion of these particles in the polymeric matrix by Iida et al. (3/15-20).

The declaration of Kenji TODORI shows the full equations dealing with the absorption characteristics and the transition probability. This would be much more instructive if the terms were properly identified and any effect of the particles size discussed. The instant specification notes that the particles sizes and their distribution affect w_0 , which clearly plays a part with respect to the absorption cross section as a function of wavelength. (see prepub at [0077-0079]) To show figure A and assert that it shows more than the trend for a certain particles is misleading as it assumes a single particle composition (ie material) and size. Clearly, the measurements are best made at the absorption maxima of the composition as this is where the absorption probability is at its maximum. Looking at the data for samples 2A-2E, the absorption saturation characteristics are the same percentage for all the samples. Sample 2D is more polydisperse as evidenced by D_{mod}/D_{bohr}. Samples 2A,2B,2C and 2E have similar modality and absorption saturation characteristics at 1MW/cm^2 and the absorption differences A_{max} are attributable to differences in particle size and composition. What would clearly establish unobvious results would be 3 nm CdSe particles dispersed in PMMA and data relating to D_{mod}, D_{mod}/D_{bohr}, A_{max}, wavelength of measurement, the absorption saturation characteristics and a discussion as to the relevance of the absorption saturation characteristics of the film in functioning as a superresolution film and why a few percent would be important. The application describes the measurement of the size of the aperture formed in the super resolution film (prepub at [0156]). This would also be interesting and clearly relevant to the use of the composition, if the applicant has data on this.

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4 THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Martin J Angebranndt whose telephone number is 571-272-1378. The examiner can normally be reached on Monday-Thursday and alternate Fridays.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark Huff can be reached on 571-272-1385. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 Moll-free).

Martin J Angebranndt Primary Examiner Art/Unit 1756

08/09/2004